

# 1000MHz 25dB Gain With GaAs Push Pull Amplifier Module

# 1. **Product profile**

## 1.1 General description

High dynamic range power doubler amplifier module operating at a supply voltage of 8VDC in an SOT115J package, using a GaAs MMIC, matching with SMT transformers at input and output port, adding ESD and surge protective devices.

## CAUTION



This device is sensitive to Electro Static Discharge (ESD). Therefore care should be taken during transport and handling.

## **1.2 Features and benefits**

- Excellent linearity
- Low noise
- Low return loss
- Rugged construction
- High reliability

## 1.3 Applications

CATV systems operating in the 40MHz to 1000MHz frequency range.

## 1.4 Quick reference data

Bandwidth 40MHz to 1000MHz; V<sub>B</sub> = 8 V;  $T_{mb}$  = 30 °C;  $Z_S$  =  $Z_L$  = 75  $\Omega$  .

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	f = 50MHz	24.5	25.0	26.0	dB
		f = 1000MHz	25.0	-	-	dB
I <sub>tot</sub>	total current	VB = 8 V	360	380	410	mA

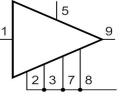
5 7 8

# 2. Pin information

Pin	Description
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### Simplified Outline

Graphic Symbol



# 3. **Operating conditions**

## 3.1 Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134) (TA = +25°C)

Parameter	Symbol	Min	Мах	Unit
Supply Voltage	VB	-	8.5	V
Input Voltage <sup>[1]</sup>	Vi	-	55	dBmV
Operating Case Temperature	Тс	-20	+90	°C
Storage Temperature	Tstg	-40	+100	°C

[1] In case of single tone

# **3.2 Recommended operating conditions** $(Zs = ZL = 75 \Omega)$

Parameter	Symbol	Test Conditions	MIN	ТҮР	MAX	Unit
Supply Voltage	Vв		7.8	8.0	8.5	V
Operating Case Temperature	Тс	.C.	-20	+30	+80	°C

# 4. Electrical characteristics

## $(T_{c} = 30 \pm 5^{\circ}C, V_{B} = 8V, Z_{S} = Z_{L} = 75 \Omega)$

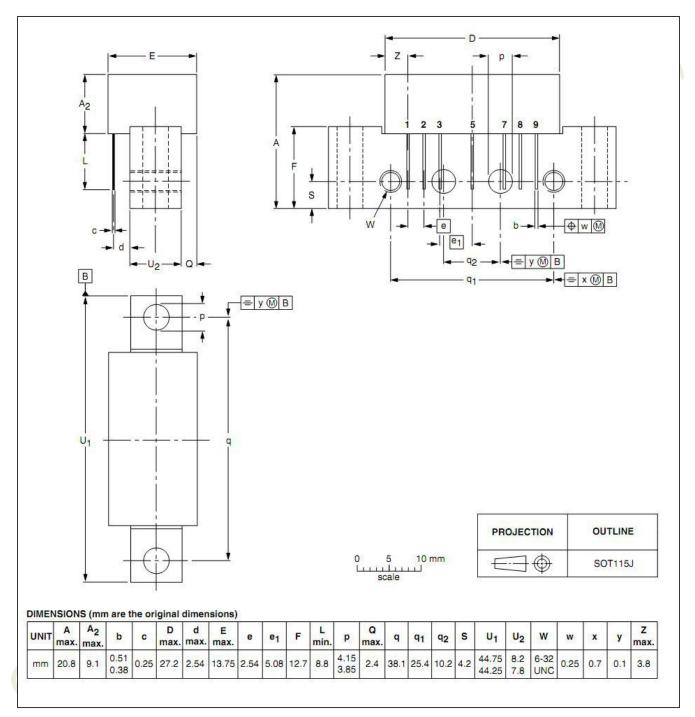
Parameter	Symbol	Test Conditions	MIN	ТҮР	МАХ	Unit
Power Gain	Gp	f = 50MHz	24.5	25.0	26.0	dB
Gain Slope	SL	f = 50 to 1000MHz	0.5	1.0	2.0	dB
Gain Flatness	FL	f = 50 to1000MHz	-	-	±0.5	dB
Noise Figure	NF	f = 1000MHz	-	5.0	5.5	dB
Operating Current	IB	VB=8VDC, RF OFF	360	380	410	mA
Composite Triple Beat	СТВ		-	-66	-	dB
Cross Modulation	ХМ	98 channels, Vo = 44dBmV at 543.25 MHz, flat output level across the band	-	-65	-	dB
Composite 2nd Order Beat	CSO		-	-68	-	dB
	S11	f = 40 to 550MHz	16	-	-	dB
Input Return Loss		f = 550 to 1000MHz	16	-	-	dB
	0.00	f = 40 to 550 MHz	16	_	_	dB
Output Return Loss	S22	f = 550 to 1000MHz	16	-	-	dB



# 5. Package outline

Rectangular single-ended package; aluminum flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads.





UNIT: mm

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